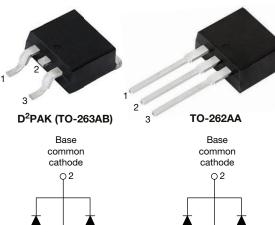
SHAY. www.vishay.com

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High Performance Schottky Rectifier, 2 x 8 A



10 Common 0 3

10 Common 0 3 Anode cathode Anode

Anode cathode Anode

VS-16CTQ ... - 1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 8 A							
V _R	60 V, 80 V, 100 V							
V _F at I _F	0.58 V							
I _{RM}	7.0 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	7.5 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop



epoxy **FREE**

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	16	А							
V _{RRM}		60 to 100	V							
I _{FSM}	t _p = 5 μs sine	850	A							
V _F	8 A_{pk} , T_J = 125 °C (per leg)	0.58	V							
TJ	Range	-55 to +175	°C							

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-16CTQ060S-M3 VS-16CTQ060-1-M3	VS-16CTQ080S-M3 VS-16CTQ080-1-M3	VS-16CTQ100S-M3 VS-16CTQ100-1-M3	UNITS				
Maximum DC reverse voltage	V _R	60	80	100	V				
Maximum working peak reverse voltage	V _{RWM}	00	00	100	v				



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ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS							
Maximum average per leg			8							
forward current per device	I _{F(AV)}	50 % duty cycle at T _C = 148 °C	16	A						
Maximum peak one cycle		^M 5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied		850						
non-repetitive surge current per leg See fig. 7	I _{FSM}			275	A					
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.50 \ A, \ L = 60$	7.50	mJ						
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maxim	0.50	А						

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		8 A	T _{.1} = 25 °C	0.72	v				
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	16 A	1j=25 C	0.88					
	VFM (*)	8 A	T ₁ = 125 °C	0.58					
		16 A	1j = 125 C	0.69					
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.55	mA				
See fig. 2	IRM (17	T _J = 125 °C	V _R = naleu V _R	7.0					
Threshold voltage	V _{F(TO)}			0.415	V				
Forward slope resistance	r _t	$T_J = T_J$ maximum		11.07	mΩ				
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal rang	500	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 n	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs				

Note

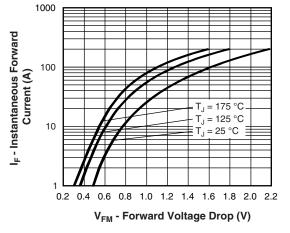
⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

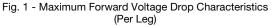
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 175	°C				
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		Р							
		R _{thJC}	DC operation	1.63	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight				2	g				
Approximate weight				0.07	oz.				
minin				6 (5)	kgf · cm				
Mounting torque	maximum			12 (10)	(lbf · in)				
Marking davias			Case style D ² PAK (TO-263AB)	16CT	QS				
Marking device			Case style TO-262AA	16CT0	ຊ1				

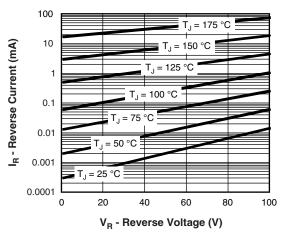


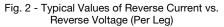
VS-16CTQ...S-M3, VS-16CTQ...-1-M3 Series

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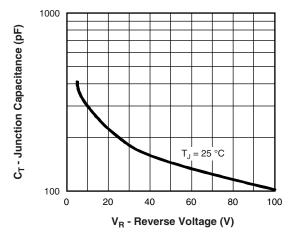


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

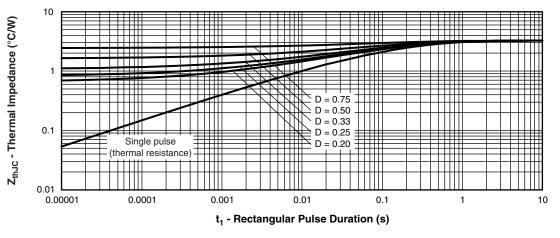


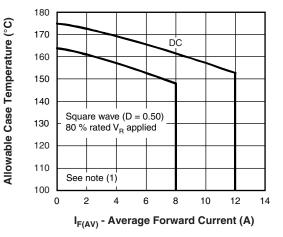
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

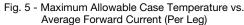
 Revision: 21-Dec-2021
 3
 Document Number: 94929

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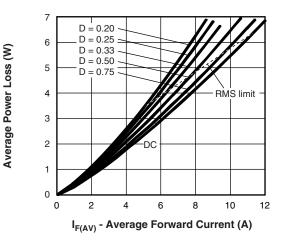


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

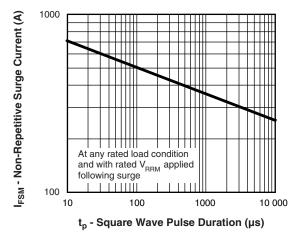


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

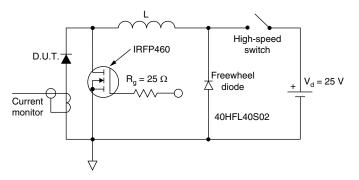


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{B1} \times I_R$ (1 - D); I_R at V_{B1} = 80 % rated V_R applied

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4

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ORDERING INFORMATION TABLE

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VISHAY

Device code	VS-	16	С	т	Q	100	S	TRL	-M3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc		Ċ
	2		,	nicondue ing (16 A		oduci			
	3 -			figuratio	-	commor	n catho	de	
	4 -		TO-220	•					
	5 -	- Sch	ottky "O	Q" series	S	0	60 = 60	V	
	6	- Vol	tage rati	ings —			80 = 80		
	7 -	• S	= D ² PA	K (TO-2	63AB)	10	00 = 10	0 V	
		• -1	= TO-2	262AA					
	8 -	• N	one = tu	ıbe					
		• TI	RL = tap	be and r	eel (left	orienteo	d - for D	² PAK (1	FO-263/
	_	• TI	RR = tap	be and r	eel (righ	nt orient	ed - for	D ² PAK	(TO-26
	9 -	- M3	3 = halo	gen-free	e, RoHS	6-compl	iant, an	d termiı	nation le

ORDERING INFORMATION									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-16CTQ060S-M3	50	Antistatic plastic tubes							
VS-16CTQ060STRL-M3	800	13" diameter plastic tape and reel							
VS-16CTQ060STRR-M3	800	13" diameter plastic tape and reel							
VS-16CTQ080S-M3	50	Antistatic plastic tubes							
VS-16CTQ080STRL-M3	800	13" diameter plastic tape and reel							
VS-16CTQ080STRR-M3	800	13" diameter plastic tape and reel							
VS-16CTQ100S-M3	50	Antistatic plastic tubes							
VS-16CTQ100STRL-M3	800	13" diameter plastic tape and reel							
VS-16CTQ100STRR-M3	800	13" diameter plastic tape and reel							
VS-16CTQ100-1-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS									
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164							
Dimensions	TO-262AA	www.vishay.com/doc?96165							
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444							
Part marking information	TO-262AA	www.vishay.com/doc?95443							
Packaging information		www.vishay.com/doc?96424							
SPICE model		www.vishay.com/doc?95279							

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

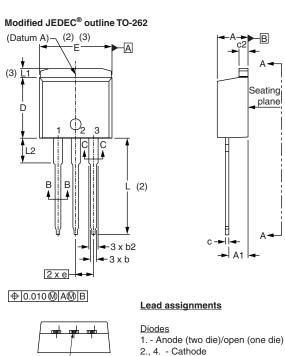
Outline Dimensions



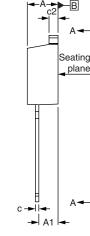
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TO-262

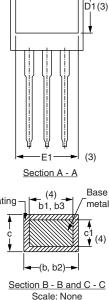
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

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